

# PC723V

\* Lead forming type (I type) and taping reel type (P type) are also available. ( PC723VI/PC723VP ) (Page 656)  
 \*\* TÜV(VDE0884) approved type as an option is also available.

## ■ Features

1. High collector-emitter voltage ( $V_{CEO}$ : 80V)
2. High isolation voltage between input and output ( $V_{iso}$ : 5 000V<sub>rms</sub>)
3. Current transfer ratio  
CTR : MIN. 50% at  $I_F=5\text{mA}$ ,  $V_{CE}=5\text{V}$
4. TTL compatible output
5. Recognized by UL, file No. E64380

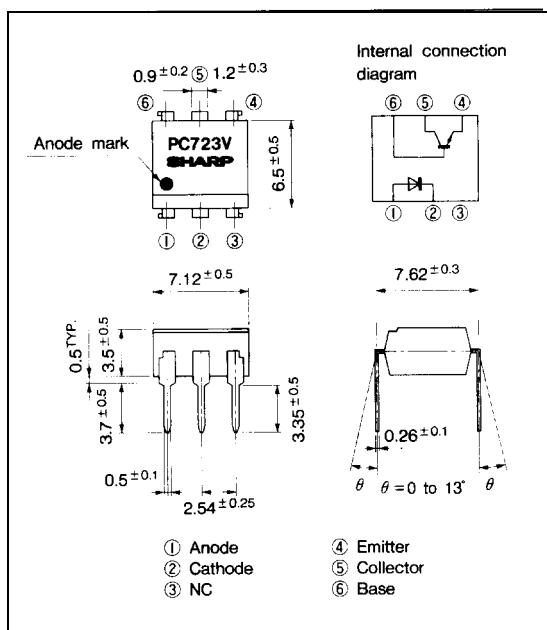
## ■ Applications

1. Telephone systems, telegram systems
2. System appliances, measuring instruments
3. Signal transmission between circuits of different potentials and impedances

## High Collector-emitter Voltage Type Photocoupler

### ■ Outline Dimensions

(Unit : mm)



## ■ Absolute Maximum Ratings

	Parameter	Symbol	Rating	Unit
Input	Forward current	$I_F$	50	mA
	* <sup>1</sup> Peak forward current	$I_{FM}$	1	A
	Reverse voltage	$V_R$	6	V
	Power dissipation	$P$	70	mW
output	Collector-emitter voltage	$V_{CEO}$	80	V
	Emitter-collector voltage	$V_{ECO}$	6	V
	Collector-base voltage	$V_{CBO}$	130	V
	Emitter-base voltage	$V_{EBO}$	6	V
	Collector current	$I_C$	50	mA
	Collector power dissipation	$P_C$	150	mW
	Total power dissipation	$P_{tot}$	200	mW
**Isolation voltage		$V_{iso}$	5000	V <sub>rms</sub>
Operating temperature		$T_{opr}$	-25 to +100	°C
Storage temperature		$T_{stg}$	-40 to +125	°C
'Soldering temperature		$T_{sol}$	260	°C

\*1 Pulse width  $\leq 100\mu\text{s}$ , Duty ratio = 0.001

\*2 40 to 60%RH, AC for 1 minute

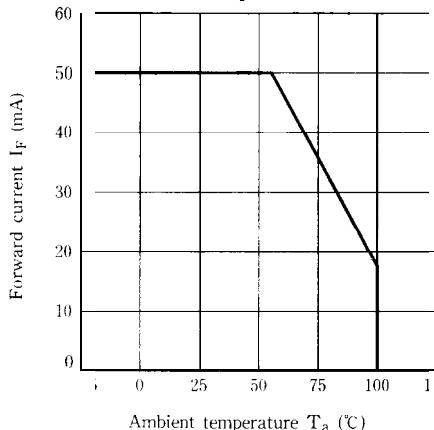
\*3 For 10 seconds

## ■ Electro-optical Characteristics

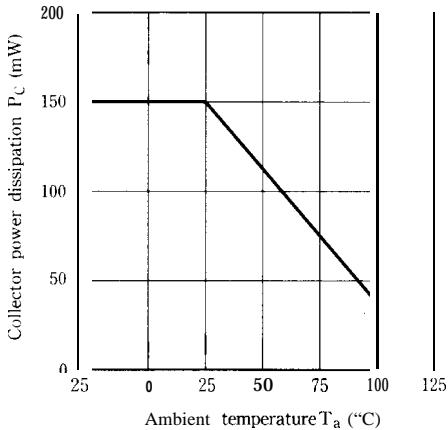
(Ta=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX	Unit
Input	Forward voltage	V <sub>F</sub>	I <sub>F</sub> =20mA		1.2	1.4	V
	Peak forward voltage	V <sub>FM</sub>	I <sub>FM</sub> =0.5A	—		3.0	V
	Reverse current	I <sub>R</sub>	V <sub>R</sub> =4V			10	μA
Output	Terminal capacitance	C <sub>t</sub>	V=0, f=1kHz	—	30	250	pF
Transfer characteristics	Collector dark current	I <sub>CEO</sub>	V <sub>CE</sub> =40V, I <sub>F</sub> =0, R <sub>BE</sub> =∞			10 <sup>-7</sup>	A
	Current transfer ratio	CTR	I <sub>F</sub> =5mA, V <sub>CE</sub> =5V, R <sub>BE</sub> =∞	50	100	400	%
charac teristics	Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>F</sub> =20mA, I <sub>C</sub> =1mA, R <sub>BE</sub> =∞	—	0.1	0.3	V
	Isolation resistance	R <sub>ISO</sub>	DC500V, 40 to 60%RH	5×10 <sup>10</sup>	10 <sup>11</sup>	—	Ω
	Floating capacitance	C <sub>f</sub>	V=0, f=1MHz	—	0.6	1.0	pF
	Cut-off frequency	f'	V <sub>CE</sub> =5V, I <sub>C</sub> =2mA, R <sub>L</sub> =100Ω, R <sub>BE</sub> =∞, -3dB	—	50	—	kHz
	Response time	t <sub>r</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =2mA		6	20	μs
		t <sub>f</sub>	R <sub>L</sub> =100Ω, R <sub>BE</sub> =∞	—	7	20	us

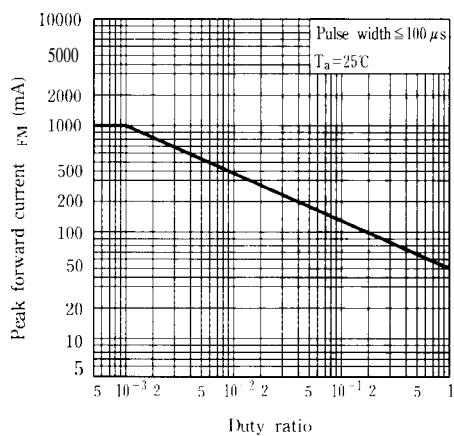
**Fig. 1 Forward Current vs. Ambient Temperature**



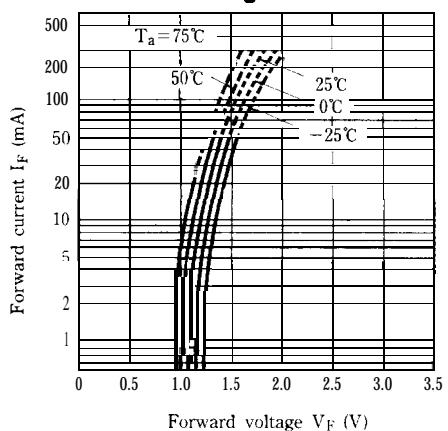
**Fig. 2 Collector Power Dissipation VS. Ambient Temperature**



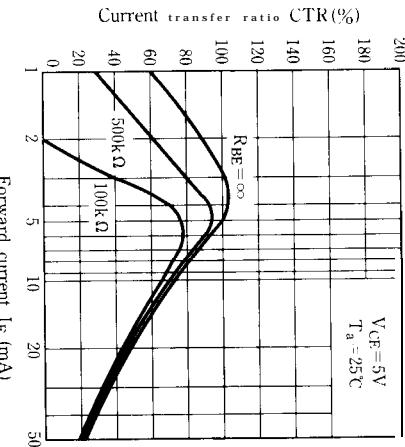
**Fig. 3 Peak Forward Current vs. Duty Ratio**



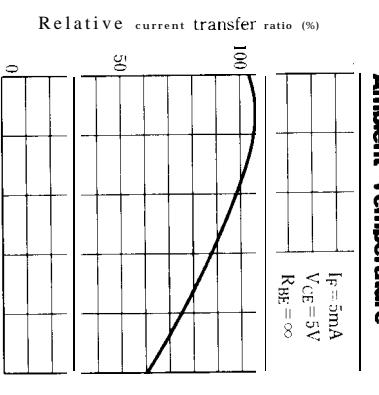
**Fig. 4 Forward Current vs. Forward Voltage**



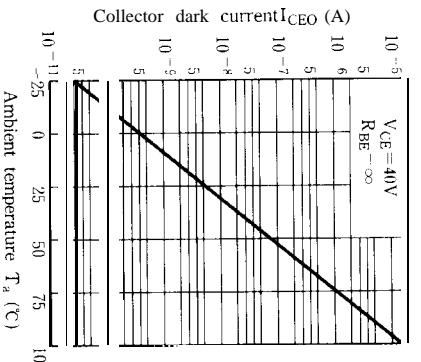
**Fig. 5 Current Transfer Ratio vs. Forward Current**



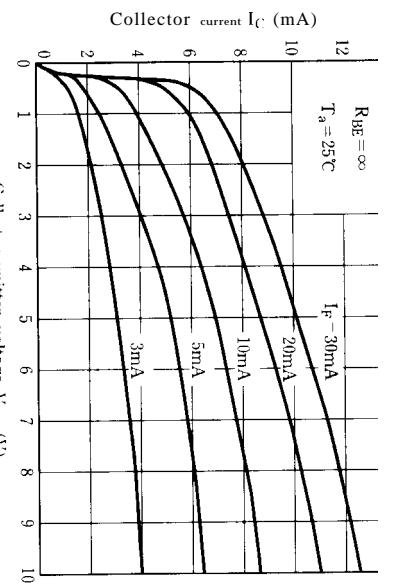
**Fig. 7 Relative Current Transfer Ratio vs. Ambient Temperature**



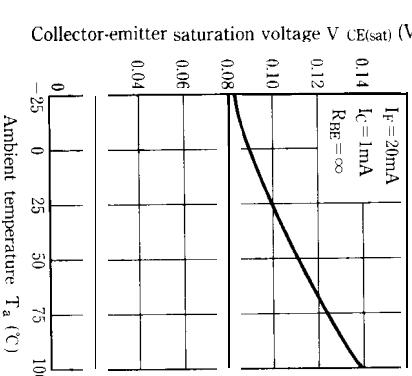
**Fig. 9 Collector Dark Current vs. Ambient Temperature**



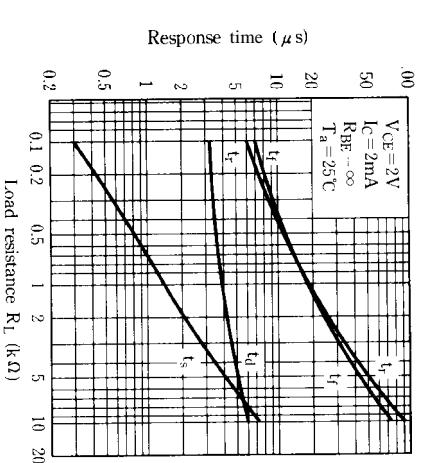
**Fig. 6 Collector Current vs. Collector-emitter Voltage**

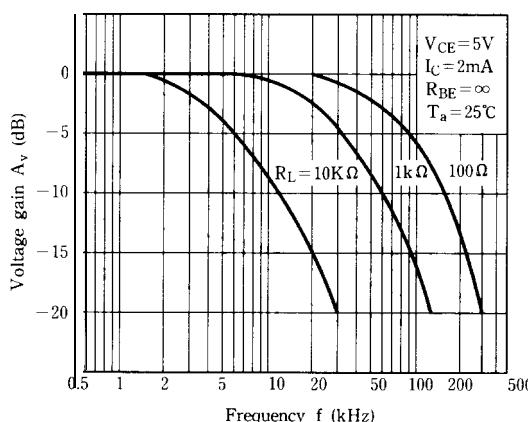
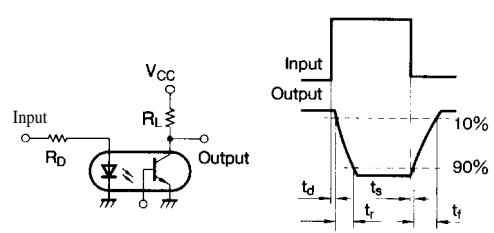
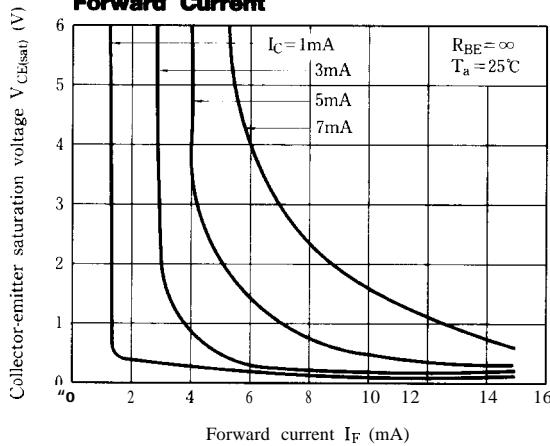
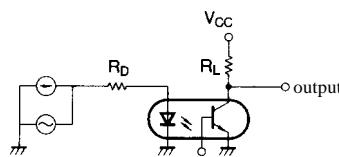


**Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature**



**Fig. 10 Response Time vs. Load Resistance**



**Fig.11 Frequency Response****Test Circuit for Response Time****Fig.12 Collector-emitter Saturation Voltage vs. Forward Current****Test Circuit for Frequency Response**

- Please refer to the chapter "Precautions for Use" (Page 78 to 93)